NSN 5961-01-137-9317

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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.330 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Pnp

Mounting Method:

Unthreaded hole

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-120.0 collector to emitter voltage/static/base open and -120.0 collector to base voltage/static/emitter open and -5.0 emitter to base

voltage, static, collector open

Current Rating Per Characteristic:

-50.00 amperes collector current, dc and -2.00 amperes base current, dc

Power Rating Per Characteristic:

300.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Transistor

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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